

MG910 GaAs Hall Element

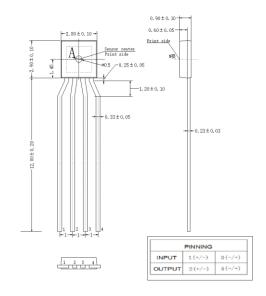
Linear GaAs Hall Element

Excellent Thermal Characteristics

Thin-type SIP Package

Shipped in Bulk by Pack (500pcs devices per pack)

Dimensional Drawing (Unit MM)



Absolute Maximum Rating

Operating Temperature Range $-40^{\circ}\text{C} \sim 125^{\circ}\text{C}$ Storage Temperature Range $-45^{\circ}\text{C} \sim 150^{\circ}\text{C}$ Maximum Input Current t_{cmax} [mA] 13mA

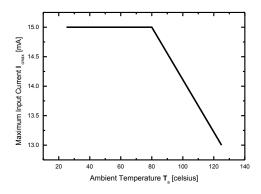


Figure 1. Maximum input current Icmax

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Electrical Characteristics (RT=25°C)

Item Symbol Test Condi. Тур. Max. Unit B = 50 mT, L = 5 mA45 mV Hall Voltage $V_{\!\scriptscriptstyle H}$ 36 54 $T_a = RT$ $B = 0mT, I_C = 0.1mA$ Input/Output Resist. 650 750 850 $\textit{R}_{\text{in/out}}$ Ω $T_a = RT$ $B = 0mT, I_C = 5mA$ Offset Voltage $V_{\scriptscriptstyle{
m OS}}$ -5 +5 mV $T_a = RT$ $B = 50 \text{mT}, I_C = 5 \text{mA},$ Temp. Coeffi. of $V_{\rm H}$ 0.06 %/°C $|\alpha V_{H}|$ $T_a = 25^{\circ}C \sim 125^{\circ}C$ B = 0mT, $I_C = 0.1mA$, %/°C Temp. Coeffi. of Rin αR_{in} 0.3 $T_a = 25^{\circ}C \sim 125^{\circ}C$ B = 0.1 - 0.4T, $I_C = 5mA$ Linearity of V_{H} ΔK -1 % $T_a = RT$

Table 1. Electrical Characteristics of MG910.

Note:

1. $V_{\rm H} = V_{\rm H-M} - V_{\rm os}$

in which $V_{\rm H-M}$ is the Output Hall Voltage, $V_{\rm H}$ is the Hall Voltage and $V_{\rm os}$ is the offset Voltage under the identical electrical stimuli.

2.
$$\alpha V_{\rm H} = \frac{1}{v_{\rm H} (T_{a1})} \times \frac{v_{\rm H} (T_{a2}) - v_{\rm H} (T_{a1})}{T_{a2} - T_{a1}} \times 100$$

$$T_{a1} = 25$$
°C, $T_{a2} = 125$ °C

3.
$$\alpha R_{\text{in}} = \frac{1}{R_{\text{in}} (T_{a1})} \times \frac{R_{\text{in}}(T_{a2}) - R_{\text{in}} (T_{a1})}{T_{a2} - T_{a1}} \times 100$$

$$T_{a1} = 25$$
°C, $T_{a2} = 125$ °C

4.
$$\Delta K = \frac{K(B_1) - K(B_2)}{\frac{K(B_1) + K(B_2)}{2}} \times 100$$
 $K = \frac{V_H}{I_c \times B}$

Characteristic Curves

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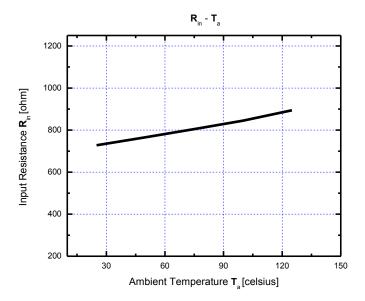


Figure 2.Input resistance R_{in} as a function of ambient temperature T_{a} .

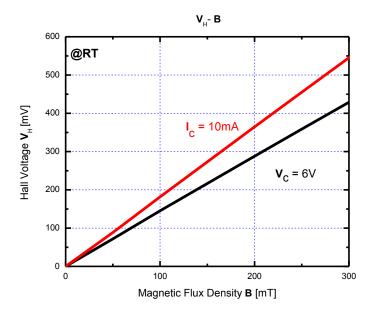


Figure 3. Hall voltage V_H as a function ofmagnetic flux density B.

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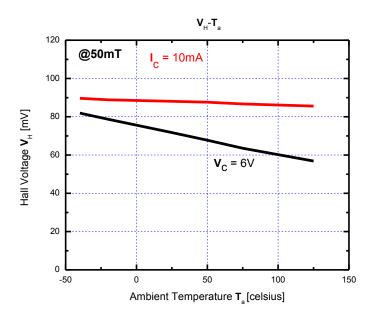


Figure 4. Hall voltage V_H as a function of ambient temperature T_a .

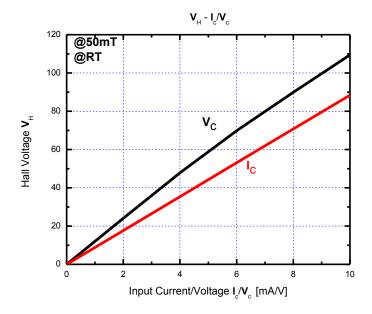


Figure 5. Hall voltage $V_{\rm H}$ as a function of electrical stimuli $I_{\rm c}/V_{\rm c.}$

Reliability Test Terms

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Table 2. Reliability Test Terms, Conditions and Durations.

No.	Terms	Conditions	Duration
1	High Temperature Storage (HTS)	[JEITA EIAJ ED-4701] 7 _a =150 (0 ~ +10) °C	1000 h
2	Heat Cycle (HC)	[JEITA EIAJ ED-4701] $T_a = -55^{\circ} \text{C} \sim 150 ^{\circ} \text{C}$ high temp normal temp low temp. 30 min - 5 min - 30 min	50 clcs
3	Temp. Humidity Storage (THS)	[JEITA EIAJ ED-4701] $T_a = 85 \pm 3 ^{\circ}\text{C}$, $R_H = 85 \pm 5 ^{\circ}\text{M}$	1000 h
4	Resist. to Hand Soldering Heat (RHSH)	[JEITA EIAJ ED-4701] Dipped in the 300±5 °C solder up to the 1 mm part from the body	5sec
5	High Temp. Operating (HTO)	\mathcal{T}_{a} =125 °C , \mathcal{V}_{c} =7.5V	1000 h

Criteria:

- Variation of Hall Voltage $\emph{V}_{\rm H}$ and input/output resistances $\emph{R}_{\rm in/out}$ are less than 20%.
- Variation of offset voltage V_{os} is less than ±16 mV.
- Other parameters in **Table 1**. are still within their ranges stated in **Table 1**.

Soldering Conditions

The following conditions should be preserved. Solder ability should be checked by yourself, because it is depend on solder paste material and other parameters.

Material of solder flux

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- Use the resin based flux and refrain from using organic or inorganic acid based and water-soluble one.

Cleansing of solder flux conditions

- Use Ethanol or Isopropyl alcohol as cleansing material.
- Process temperature should be 50 °C or less.
- Duration should be 5 min or less.

Hand soldering conditions

- Apart from the mold resin more than 1mm.
- Solder at temperature 300 °C for less than 5s.

Wave soldering conditions

- Temperature in Pre-heating zone should be lower than 150°C.
- Temperature in Soldering zone should be lower than 280°C.

Precautions for ESD

This product is the device that is sensitive to ESD (Electrostatic Discharge). Handling Hall Elements with the ESD-Caution mark under the environment in which

- Static electrical charge is unlikely to arise. (Ex; Relative Humidity; over 40%RH).
- Wearing the antistatic suit and wristband when handling the devices.
- Implementing measures against ESD as for containers that directly touch the devices.

Precautions for Storage

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- Products should be stored at an appropriate temperature and humidity (5 to 35°C, 40 to 60%RH) after the unsealing of MBB. **Using self-sealer is highly recommended**. Keeping products away from chlorine and corrosive gas.

- Long-term storage

Products are sealed in MBB with a desiccant and partially a moisture indicator. The moisture indicator should be checked right after the unsealing of MBB. If the moisture indicator reveals the internal moisture is above 50%HR, please contact the local distributor.

For storage longer than 2 years, it is recommended to store in nitrogen atmosphere with MBB sealed.
 Oxygen and H₂O of atmosphere oxidizes leads of products and lead solder ability get worse.

Precautions for Safety

- Do not alter the form of this product into a gas, powder or liquid through burning, crushing or chemical processing.
- Observe laws and company regulations when discarding this product.